The HD74LS373, 8-bit register features totem-pole three-state outputs designed specifically for driving highly-capacitive or relatively low-impedance loads. The high-impedance third state and increased high-logic-level drive provide this register with the capacity of being connected directly to and driving the bus lines in a bus-organized system without need for interface or pull-up components. They are particularly attractive for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

The eight latches are transparent D-type latches meaning that while the enable (G) is high the Q outputs will follow the data (D) inputs. When the enable is taken low the output will be latched at the level of the data that was setup.

# FUNCTION TABLE

	Output				
Output control	Enable G	D	Q		
L	н	Н	н		
L	Н	L.	L		
L	L ×		Q <sub>o</sub>		
Н	×	×	Z		

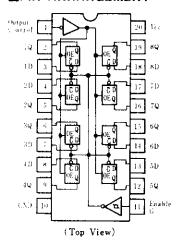
Notes: H = high level, L = low level,

X = irrelevant

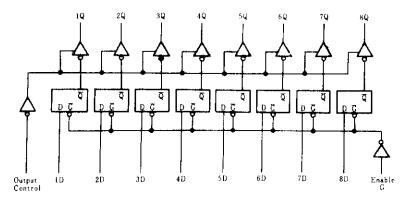
Q<sub>0</sub> = level of Q before the indicated steady-state input conditions were established.

Z = off (high-impedance) state of a three-state output

#### **PIN ARRANGEMENT**



#### ■BLOCK DIAGRAM



### **MRECOMMENDED OPERATING CONDITIONS**

Item		Symbol	min	typ	max	Unit
Supply voltage		$V_{cc}$	4.75	5.00	5.25	V
Output voltage		$V_{OH}$			5.5	V
Output current		1 он	_	_	-2.6	mА
		Ior			24	mA
Enable pulse "H" level			15			
width	"L" level	l w	15	_		ns
Data setup time		t su	5↓	-		ns
Data hold time		t s	25 ↓		_	ns

Note) 4: The arrow indicates the falling edge of clock pulse.

# **ELECTRICAL CHARACTERISTICS** $(Ta=-20\sim+75^{\circ}C)$

Item	Symbol	Test Conditions		min	typ*	max	Unit	
	VIH			2.0	_		V	
Input voltage		Data inputs				0.7	V	
	V <sub>IL</sub>	G, Output control inputs		_	0.8	<b>v</b>		
	Von	$V_{CC} = 4.75 \text{V}, \ V_{IH} = 2 \text{V}, \ V_{IL} = V_{I}$	L mex, I <sub>OH</sub> = -2.6mA	2.4			V	
Output voltage		$V_{cc}-4.75V$ , $V_{IB}-2V$ ,	Io1-12mA	_		0.4	v	
	Vol	VIL - VIL max	IoL = 24mA			0.5	V	
Off-state output current Iozu	Іогн		Vo-2.7V			20	μΑ	
	Iozi	$V_{\rm cc} = 5.25 \text{V}, V_{tH} = 2 \text{V}$	Vo-0.4V	_		-20		
	In	$V_{cc} = 5.25 \text{V}, V_l = 2.7 \text{V}$				20	μA	
Input current	In.	$V_{cc}$ = 5.25V, $V_{t}$ = 0.4V			0.4	mA		
	I,	Vcc-5.25V, V1-7V	_		0.1	mA		
Short-circuit output current	Ios	Vcc-5.25V	-30		-130	mA		
Supply current	Icc	Vcc-5.25V, Vi-4.5V (Output control)		_	24	40	mA	
Input clamp voltage	Vik	$V_{cc}=4.75$ V, $I_{IN}=-18$ mA			-1.5	V		

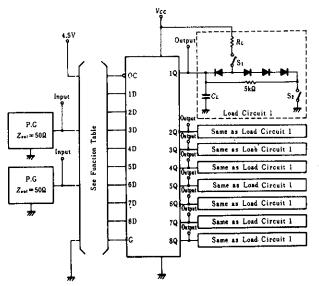
<sup>\*</sup> VCC=5V, Ta=25°C

# **ESWITCHING CHARACTERISTICS** $(V_{cc}=5\text{V}, T_a=25^{\circ}\text{C})$

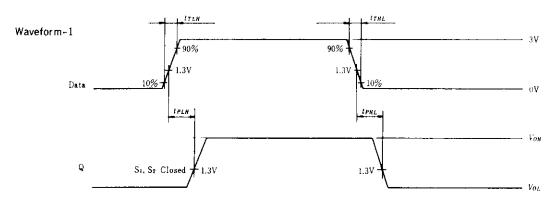
Item	Symbol	Input	Output	Test Conditions	min	typ	max	Unit
Propagation delay time	t <sub>PLH</sub>				_	12	18	
	tpHL	D Q			12	18		
	t <sub>PLH</sub>			C <sub>L</sub> -45pF		20	30	
	t <sub>PHL</sub>	G	Q	$R_L = 667\Omega$		18	30	
Output enable time	t <sub>ZH</sub>	ос	Q		_	15	28	n\$
	l ZL				_	25	36	
Output disable time	t <sub>HZ</sub>			$C_{L}=5pF$		12	20	
	t <sub>LZ</sub>	oc	Q	$R_L = 667\Omega$		15	25	

# TESTING METHOD

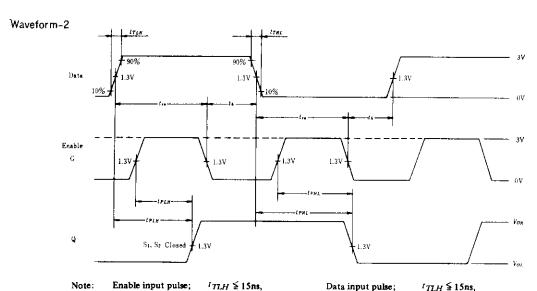
Test Circuit

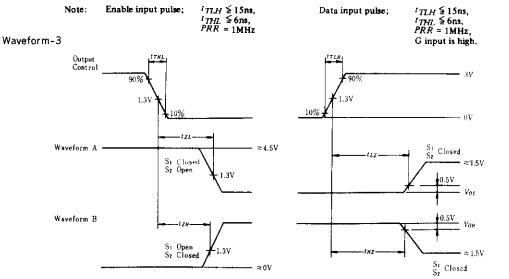


 C<sub>L</sub> includes probe jig capacitance.
 All diodes are 1\$2074 (f). Notes:



Notes: Input pulse;  $t_{TLH} \le 15$ ns,  $t_{THL} \le 6$ ns, PRR = 1MHz, duty cycle 50%

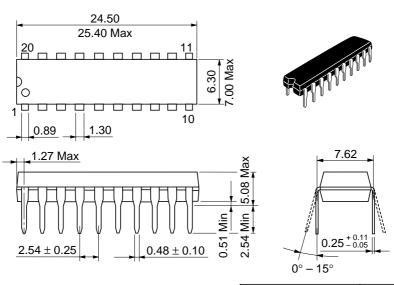




Notes:

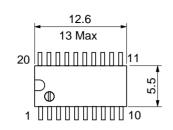
 Input pulse; t<sub>TLH</sub> ≤ 15ns, t<sub>THL</sub> ≤ 6ns, PRR = iMHz, duty cycle 50%
 Waveform A if for an output with internal conditions such that the output is low except when disabled by the output control. Waveform B is for an output with internal conditions such that the output is high except when disabled by the output control.

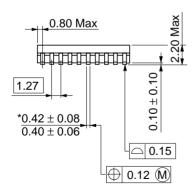
Unit: mm

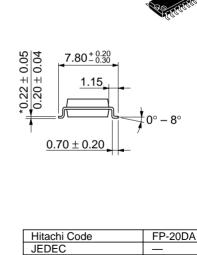


Hitachi Code	DP-20N
JEDEC	_
EIAJ	Conforms
Weight (reference value)	1.26 g

Unit: mm







Weight (reference value)

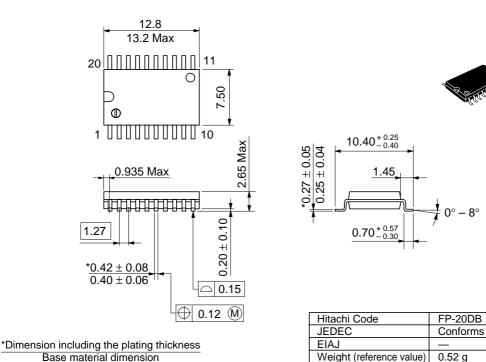
Conforms

0.31 g

EIAJ

\*Dimension including the plating thickness
Base material dimension

Unit: mm



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